

DECLARATION AND POWER OF ATTORNEY FOR PATENT APPLICATION

As below named inventors, we hereby declare that:

Our residence, post office address and citizenship are as stated below next to our names;

We believe we are the original, first and sole joint inventors of the subject matter which is claimed and for which a patent is sought on the invention entitled:

METHOD FOR CONTROLLING OUTER LOOP POWER

the specification of which: (check one)

xx is attached.

_____ was filed on _____
under Attorney's Docket Number _____
as Application Serial No. _____
and was amended on _____ (if applicable).

We hereby state that we have reviewed and understand the contents of the above identified specification, including the claims, as amended by any amendment referred to above.

We acknowledge the duty to disclose information which is material to the patentability of this application in accordance with 37 CFR § 1.56.

We claim priority benefits under Title 35, United States Code § 119 of any foreign application(s) for patent or inventor's certificate listed below, specifying the application number, country, day, month, and year of its filing. We identify the foreign application on which we claim priority by indicating this in the below, right-hand column. We identify below any foreign application having a filing date which is earlier than that of the application on which priority is claimed:

Prior Foreign Application(s): Priority Claimed

Number	Country	(Day/Month/Year)	(yes/no)
CN00116996.3	China	July 1, 2000	Yes

We claim the benefit under Title 35, United States Code, §120 of any United States application(s) listed below, and, insofar as the subject matter of each of the claims of this application is not disclosed in the prior United States application in the manner provided by the first paragraph of Title 35, United States Code, § 112, we acknowledge the duty to disclose to the United States Patent and Trademark Office all information known to me to be material to patentability as defined in Title 37, Code of Federal Regulations, § 1.56 which became available between the filing date of the prior application and the national or PCT international filing date of this application.

Application Serial No.	Filing Date	Status (patented, pending, abandoned)
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We hereby declare that all statements made herein of our own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under 18 U.S.C. § 1001 and that such willful false statements may jeopardize the validity of the application or any patent issued thereon.

POWER OF ATTORNEY: As named inventors, we hereby appoint Angelo J. Bufalino, 29,622, James T. FitzGibbon, Reg. No. 20,592, Ludwig Kolman, Reg. No. 32,473, Thomas D. Paulius, 30,792 and Richard A. Zachar, Reg. No. 25,560, Michael J. Turgeon, Reg. No. 39,404 and Matthew P. Pasulka, Reg. No. 42,981, as my attorneys with full power of substitution and revocation, to prosecute this application and to transact all business in the Patent and Trademark Office in connection therewith. Address all correspondence to:

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